Technical Documents

Support \& Community

# TS5A22364 0.65-』 Dual SPDT Analog Switches With Negative Signaling Capability 

## 1 Features

- Specified Break-Before-Make Switching
- Negative Signaling Capability: Maximum Swing from -2.75 V to $2.75 \mathrm{~V}\left(\mathrm{~V}_{\mathrm{Cc}}=2.75 \mathrm{~V}\right)$
- Internal Shunt Switch Prevents Audible Click-andPop When Switching Between Two Sources
- Low ON-State Resistance ( $0.65 \Omega$ Typical)
- Low Charge Injection
- Excellent ON-State Resistance Matching
- 2.3-V to $5.5-\mathrm{V}$ Power Supply (V $\mathrm{V}_{\mathrm{Cc}}$ )
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
- 2500-V Human-Body Model (A114-B, Class II)
- 1500-V Charged-Device Model (C101)
- 200-V Machine Model (A115-A)


## 2 Applications

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio Routing
- Medical Imaging


## 3 Description

The TS5A22364 is a bidirectional, 2-channel, singlepole double-throw (SPDT) analog switch designed to operate from 2.3 V to 5.5 V . The device features negative signal capability that allows signals below ground to pass through the switch without distortion. Additionally, the TS5A22364 includes an internal shunt switch, which automatically discharges any capacitance at the NC or NO terminals when they are unconnected to COM. This reduces the audible click/pop noise when switching between two sources. The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance are ideal for audio applications. The $3.00-\mathrm{mm} \times 3.00-\mathrm{mm}$ DRC package is also available as a nonmagnetic package for medical imaging applications.

| Device Information ${ }^{(1)}$ |  |  |
| :---: | :---: | :---: |
| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
| TS5A22364 | VSON (10) | $3.00 \mathrm{~mm} \times 3.00 \mathrm{~mm}$ |
|  | DSBGA (10) | $1.90 \mathrm{~mm} \times 1.40 \mathrm{~mm}$ |
|  | VSSOP (10) | $3.00 \mathrm{~mm} \times 3.00 \mathrm{~mm}$ |
| (1) For all availab the end of the | packages, see a sheet. | derable addendum |

Device Information ${ }^{(1)}$
available packages, see the orderable addendum at the end of the data sheet.


## Table of Contents

1 Features ..... 1
2 Applications ..... 1
3 Description ..... 1
4 Revision History. ..... 2
5 Pin Configuration and Functions ..... 3
6 Specifications ..... 4
6.1 Absolute Maximum Ratings ..... 4
6.2 ESD Ratings ..... 4
6.3 Recommended Operating Conditions ..... 4
6.4 Thermal Information ..... 5
6.5 Electrical Characteristics for 2.5-V Supply ..... 5
6.6 Electrical Characteristics for 3.3-V Supply ..... 6
6.7 Electrical Characteristics for 5-V Supply ..... 8
6.8 Typical Characteristics ..... 9
7 Parameter Measurement Information ..... 11
8 Detailed Description ..... 15
8.1 Overview ..... 15
8.2 Functional Block Diagram ..... 15
8.3 Feature Description ..... 16
8.4 Device Functional Modes ..... 16
9 Application and Implementation ..... 17
9.1 Application Information. ..... 17
9.2 Typical Application ..... 17
10 Power Supply Recommendations ..... 19
11 Layout. ..... 19
11.1 Layout Guidelines ..... 19
11.2 Layout Example ..... 19
12 Device and Documentation Support ..... 20
12.1 Receiving Notification of Documentation Updates ..... 20
12.2 Community Resources. ..... 20
12.3 Trademarks ..... 20
12.4 Electrostatic Discharge Caution. ..... 20
12.5 Glossary ..... 20
13 Mechanical, Packaging, and Orderable Information ..... 20

## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.
Changes from Revision G (September 2015) to Revision H Page

- Changed the $\mathrm{V}_{\mathrm{IN}}$ MAX value From: $\mathrm{V}_{\mathrm{CC}}$ To: 5.5 V in the Recommended Operating Conditions table ..... 4
Changes from Revision F (June 2015) to Revision G Page
- Changed $C_{L}$ TEST CONDITION value for all THD PARAMETERs from 15 pf to 35 pf . ..... 7
Changes from Revision E (May 2013) to Revision F Page
- Added Pin Configuration and Functions section, ESD Ratings table, Recommended Operating Conditions table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section ..... 1
- Split the TS5A22364 and TS5A22362 into separate datasheets and added verbiage to clarify the operation of the shunt resistor. ..... 1
- Changed the max $R_{\text {on }}$ spec from $1.04 \Omega$ to $1.30 \Omega$ at $2.7 \mathrm{~V} \mathrm{~V}_{\mathrm{CC}}$ across full $\mathrm{T}_{\mathrm{A}}$. ..... 5
Changes from Revision D (November 2011) to Revision E Page
- Added Absolute Maximum Ratings textnote ..... 4
Changes from Revision C (April 2010) to Revision D Page
- Added Medical Imaging to Applications. ..... 1


## 5 Pin Configuration and Functions


*The exposed center pad, if used, must be connected as a secondary GND or left electrically open.


Pin Functions

| PIN |  |  | TYPE | DESCRIPTION |  |
| :--- | :---: | :---: | :---: | :--- | :---: |
| NAME | DRC / DGS | YZP |  |  |  |
| VCC | 1 | A2 | - | Power Supply |  |
| NO1 | 2 | A3 | I/O | Normally Open (NO) signal path, Switch 1 |  |
| COM1 | 3 | B3 | I/O | Common signal path, Switch 1 |  |
| NC1 | 4 | C3 | I/O | Normally Closed (NC) signal path, Switch 1 |  |
| IN1 | 5 | D3 | I | Digital control pin to connect COM1 to NO1, Switch 1 |  |
| GND | 6 | D2 | - | Ground |  |
| IN2 | 7 | D1 | I | Digital control pin to connect COM2 to NO2, Switch 2 |  |
| NC2 | 8 | C1 | I/O | Normally Closed (NC) signal path, Switch 2 |  |
| COM2 | 9 | B1 | I/O | Common signal path, Switch 2 |  |
| NO2 | 10 | A1 | I/O | Normally Open (NO) signal Path, Switch 2 |  |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1) (2)

|  |  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage ${ }^{(3)}$ |  | -0.5 | 6 | V |
| $\mathrm{V}_{\mathrm{NC}}$ <br> $\mathrm{V}_{\mathrm{NO}}$ <br> $\mathrm{V}_{\mathrm{COM}}$ | Analog voltage ${ }^{(3)(4)(5)}$ |  | $\mathrm{V}_{C C}-6$ | $V_{C C}+0.5$ | V |
| $\mathrm{I}_{\text {I/OK }}$ | Analog port diode current | $\mathrm{V}_{\mathrm{NC}}, \mathrm{~V}_{\mathrm{NO}}, \mathrm{~V}_{\mathrm{COM}}<0$ or $\mathrm{V}_{\mathrm{NC}}, \mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{COM}}>\mathrm{V}_{\mathrm{CC}}$ | -50 | 50 | mA |
| $\begin{array}{\|l\|} \hline I_{\mathrm{NC}} \\ \mathrm{I}_{\mathrm{NO}} \\ \mathrm{I}_{\mathrm{COM}} \\ \hline \end{array}$ | ON-state switch current | $\mathrm{V}_{\mathrm{NC}}, \mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{COM}}=0$ to $\mathrm{V}_{\mathrm{CC}}$ | -150 | 150 | mA |
|  | ON-state peak switch current ${ }^{(6)}$ |  | -300 | 300 |  |
| $\mathrm{I}_{\text {RSH }}$ | OFF-state switch Shunt Resistor current |  | -20 | 20 |  |
| $\begin{array}{\|l\|l\|} \hline \mathrm{I}_{\mathrm{NC}}{ }^{(3)}(7)(8) \\ \mathrm{I}_{\mathrm{NO}}{ }^{(3)(7)(8)} \\ \mathrm{I}_{\mathrm{COM}}{ }^{(3)(7)(8)} \\ \hline \end{array}$ | ON-state switch current | $\mathrm{V}_{\mathrm{NC}}, \mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{COM}}=0$ to $\mathrm{V}_{\mathrm{CC}}$ | -350 | 350 | mA |
|  | ON-state peak switch current ${ }^{(6)}$ |  | -500 | 500 |  |
| $\mathrm{V}_{\mathrm{IN}}$ | Digital input voltage range |  | -0.5 | 6.5 | V |
| $\mathrm{I}_{\mathrm{IK}}$ | Digital input clamp current ${ }^{(3)}{ }^{(4)}$ | $V_{1}<0$ | -50 | 50 | mA |
| $\mathrm{I}_{\mathrm{CC}}$ $I_{\text {GND }}$ | Continuous current through $\mathrm{V}_{\mathrm{CC}}$ or GND |  | -100 | 100 | mA |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature |  | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability
(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(3) All voltages are with respect to ground, unless otherwise specified.
(4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(5) This value is limited to 5.5 V maximum.
(6) Pulse at 1 -ms duration $<10 \%$ duty cycle.
(7) $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to $5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$.
(8) For YZP package only.

### 6.2 ESD Ratings

|  |  | VALUE | UNIT |
| :---: | :---: | :---: | :---: |
| Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ${ }^{(1)}$ | $\pm 2500$ | V |
|  | $\underset{(2)}{\text { Charged-device model (CDM), per JEDEC specification JESD22-C101 }}$ | $\pm 1500$ |  |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than $500-\mathrm{V}$ HBM is possible with the necessary precautions.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|  |  | MIN | MAX | UNIT |
| :--- | :--- | ---: | :---: | :---: |
| $V_{C C}$ | Supply voltage | 2.3 | 5.5 | V |
| $\mathrm{~V}_{\mathrm{NC}}$ | Signal path voltage | $\mathrm{V}_{\mathrm{CC}}-5.5$ | $\mathrm{~V}_{\mathrm{CC}}$ | V |
| $\mathrm{V}_{\mathrm{NO}}$ |  |  |  |  |
| $\mathrm{V}_{\mathrm{COM}}$ |  | GND | 5.5 | V |
| $\mathrm{~V}_{\mathrm{IN}}$ | Digital control |  |  |  |

### 6.4 Thermal Information

| THERMAL METRIC ${ }^{(1)}$ |  | TS5A22364 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | DGS (VSSOP) | DRC (VSON) | YZP (DSBGA) |  |
|  |  | 10 PINS | 10 PINS | 10 PINS |  |
| $\mathrm{R}_{\text {өJA }}$ | Junction-to-ambient thermal resistance | 163.3 | 44.3 | 90.9 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {日JC }}$ (top) | Junction-to-case (top) thermal resistance | 56.4 | 70.1 | 0.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {өJB }}$ | Junction-to-board thermal resistance | 83.1 | 19.3 | 8.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\psi$ JT | Junction-to-top characterization parameter | 6.8 | 2.0 | 3.2 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\Psi_{\text {JB }}$ | Junction-to-board characterization parameter | 81.8 | 19.4 | 8.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {日JC(bot) }}$ | Junction-to-case (bottom) thermal resistance | N/A | 6.2 | N/A | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

### 6.5 Electrical Characteristics for 2.5-V Supply

$\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{\mathrm{Cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\text {COM }}$, <br> $\mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{NC}}$ | Analog signal range |  |  |  |  | $V_{C C}-5.5$ |  | $\mathrm{V}_{\mathrm{Cc}}$ | V |
| $\mathrm{R}_{\text {on }}$ | ON-state resistance | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}, 1.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{CC}}-5.5 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 0.65 | 0.94 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 1.3 |  |
|  |  |  |  | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 0.65 | 0.94 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 1.3 |  |
| $\Delta \mathrm{R}_{\text {on }}$ | ON-state resistance match between channels | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1.5 \mathrm{~V}$, $\mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}$, | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 0.023 | 0.11 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.15 |  |
| $\mathrm{R}_{\text {on(flat) }}$ | ON-state resistance flatness | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}, 1.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{CC}}-5.5 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 0.18 | 0.46 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.5 |  |
| $\mathrm{R}_{\text {SH }}$ | Shunt switch resistance | $\mathrm{I}_{\mathrm{NO}}$ or $\mathrm{I}_{\mathrm{NC}}=10 \mathrm{~mA}$ |  | Full | 2.7 V |  | 25 | 50 | $\Omega$ |
| $\mathrm{I}_{\text {COM (ON) }}$ | COM ON leakage current | $\mathrm{V}_{\mathrm{NC}}$ and $\mathrm{V}_{\mathrm{NO}}=$ Floating, <br> $\mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \mathrm{V}_{\mathrm{CC}}-5.5 \mathrm{~V}$, | See Figure 15 | $25^{\circ} \mathrm{C}$ | 2.7 V | -50 |  | 50 | nA |
|  |  |  |  | Full |  | -375 |  | 375 |  |
| DIGITAL CONTROL INPUTS (IN) ${ }^{(2)}$ |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Input logic high |  |  | Full |  | 1.4 |  | 5.5 | V |
| $\mathrm{V}_{\text {IL }}$ | Input logic low |  |  |  |  |  |  | 0.4 |  |
| $\mathrm{I}_{\mathrm{IH}}, \mathrm{I}_{\mathrm{IL}}$ | Input leakage current | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {CC }}$ or 0 |  | $25^{\circ} \mathrm{C}$ | 2.7 V | -250 |  | 250 | nA |
|  |  |  |  | Full |  | -250 |  | 250 |  |

[^0]
## Electrical Characteristics for 2.5-V Supply (continued)

$\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\mathrm{A}}$ | $\mathrm{V}_{\text {cc }}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DYNAMIC |  |  |  |  |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{ON}}$ | Turnon time | $\begin{aligned} & V_{C O M}=V_{C C}, \\ & R_{L}=300 \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ <br> see Figure 17 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 44 | 80 | ns |
|  |  |  |  | Full | $\begin{aligned} & \text { 2.3 V to } \\ & 2.7 \mathrm{~V} \end{aligned}$ |  |  | 120 |  |
| $\mathrm{t}_{\text {OFF }}$ | Turnoff time | $\begin{aligned} & V_{C O M}=V_{C C}, \\ & R_{L}=300 \Omega \end{aligned}$ | $\begin{aligned} & C_{\mathrm{L}}=35 \mathrm{pF} \\ & \text { see Figure } 17 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 22 | 70 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.3 \mathrm{~V} \text { to } \\ & 2.7 \mathrm{~V} \end{aligned}$ |  |  | 70 |  |
| $t_{\text {BBM }}$ | Break-before-make time | See Figure 18 |  | $25^{\circ} \mathrm{C}$ | 2.5 V | 1 | 7 |  | ns |
| $\mathrm{Q}_{\mathrm{C}}$ | Charge injection | $\mathrm{V}_{\mathrm{GEN}}=0, \mathrm{R}_{\text {GEN }}=0$ | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}$, see Figure 22 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 215 |  | pC |
| $\mathrm{C}_{\text {COM(ON) }}$ | NC, NO, COM ON capacitance | $\begin{aligned} & V_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}} \text { or } \mathrm{GND}, \\ & \text { Switch ON, } \mathrm{f}=10 \mathrm{MHz} \end{aligned}$ | See Figure 16 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 370 |  | pF |
| $\mathrm{C}_{1}$ | Digital input capacitance | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {CC }}$ or GND | See Figure 16 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 2.6 |  | pF |
| BW | Bandwidth | $\mathrm{R}_{\mathrm{L}}=50 \Omega,-3 \mathrm{~dB}$ |  | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 17 |  | MHz |
| OISo | OFF isolation | $\mathrm{R}_{\mathrm{L}}=50 \Omega$ | $\begin{aligned} & \mathrm{f}=100 \mathrm{kHz} \text {, see } \\ & \text { Figure } 20 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 2.5 V |  | -66 |  | dB |
| $\mathrm{X}_{\text {TALK }}$ | Crosstalk | $\mathrm{R}_{\mathrm{L}}=50 \Omega$ | $\begin{aligned} & f=100 \mathrm{kHz}, \\ & \text { see Figure } 21 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 2.5 V |  | -75 |  | dB |
| THD | Total harmonic distortion | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}, \end{aligned}$ | $\begin{aligned} & f=20 \mathrm{~Hz} \text { to } \\ & 20 \mathrm{kHz} \text {, see Figure } 23 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 0.01\% |  |  |
| SUPPLY |  |  |  |  |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{CC}}$ | Positive supply current | $\mathrm{V}_{\mathrm{COM}}$ and $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND, <br> $\mathrm{V}_{\mathrm{NC}}$ and $\mathrm{V}_{\mathrm{NO}}=$ Floating |  | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 0.2 | 1.1 | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  |  |  | 1.3 |  |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}-5.5, \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \text { or } \mathrm{GND}, \\ & \mathrm{~V}_{\mathrm{NC}} \text { and } \mathrm{V}_{\mathrm{NO}}=\text { Floating } \end{aligned}$ |  | Full | 2.7 V |  |  | 3.3 | $\mu \mathrm{A}$ |

### 6.6 Electrical Characteristics for 3.3-V Supply

$\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\text {COM }}$, <br> $\mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{NC}}$ | Analog signal range |  |  |  |  | $\mathrm{V}_{\mathrm{CC}}-5.5$ |  | $\mathrm{V}_{\mathrm{Cc}}$ | V |
| $\mathrm{R}_{\text {on }}$ | ON-state resistance | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{\mathrm{CC}}, 1.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{CC}}-5.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 3 V |  | 0.61 | 0.87 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.97 |  |
| $\Delta \mathrm{R}_{\text {on }}$ | ON-state resistance match between channels | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=1.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 3 V |  | 0.024 | 0.13 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.13 |  |
| $\mathrm{R}_{\text {on(flat) }}$ | ON-state resistance flatness | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{\mathrm{CC}}, 1.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{CC}}-5.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 3 V |  | 0.12 | 0.46 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.5 |  |
| $\mathrm{R}_{\text {SH }}$ | Shunt switch resistance | $\mathrm{I}_{\mathrm{NO}}$ or $\mathrm{I}_{\mathrm{NC}}=10 \mathrm{~mA}$ |  | Full | 3 V |  | 25 | 37 | $\Omega$ |
| $\mathrm{I}_{\text {COM }}(\mathrm{ON}$ ) | COM ON leakage current | $\mathrm{V}_{\mathrm{NC}}$ and $\mathrm{V}_{\mathrm{NO}}=$ Open, <br> $\mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \mathrm{V}_{\mathrm{CC}}-5.5 \mathrm{~V}$, | COM to NO or NC, see Figure 15 | $25^{\circ} \mathrm{C}$ | 3.6 V | -50 |  | 50 | nA |
|  |  |  |  | Full |  | -375 |  | 375 |  |
| DIGITAL CONTROL INPUTS (IN) ${ }^{(2)}$ |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Input logic high |  |  | Full |  | 1.4 |  | 5.5 | V |
| $\mathrm{V}_{\text {IL }}$ | Input logic low |  |  |  |  |  |  | 0.6 |  |
| $\mathrm{IIH}_{\mathrm{H}}, \mathrm{IIL}^{\text {l }}$ | Input leakage current | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or 0 |  | $25^{\circ} \mathrm{C}$ | 3.6 V | -250 |  | 250 | nA |
|  |  |  |  | Full |  | -250 |  | 250 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All digital inputs of the device must be held at $\mathrm{V}_{\mathrm{CC}}$ or GND to ensure proper device operation. Floating digital inputs will cause excessive current consumption. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

## Electrical Characteristics for 3.3-V Supply (continued)

$\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDI | TIONS | TA | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DYNAMIC |  |  |  |  |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{ON}}$ | Turnon time | $\begin{aligned} & V_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ & \text { see Figure } 17 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 34 | 80 | ns |
|  |  |  |  | Full | $\begin{aligned} & 3 \mathrm{~V} \text { to } \\ & 3.6 \mathrm{~V} \end{aligned}$ |  |  | 120 |  |
| $\mathrm{t}_{\text {OFF }}$ | Turnoff time | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ & \text { see Figure } 17 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 19 | 70 | ns |
|  |  |  |  | Full | $\begin{aligned} & 3 \mathrm{~V} \text { to } \\ & 3.6 \mathrm{~V} \end{aligned}$ |  |  | 70 |  |
| $t_{\text {BBM }}$ | Break-before-make time | See Figure 18 |  | $25^{\circ} \mathrm{C}$ | 3.3 V | 1 | 7 |  | ns |
| $\mathrm{Q}_{\mathrm{C}}$ | Charge injection | $\begin{aligned} & \mathrm{V}_{\mathrm{GEN}}=0, \\ & \mathrm{R}_{\mathrm{GEN}}=0, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF},$ <br> see Figure 22 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 300 |  | pC |
| $\mathrm{C}_{\text {COM(ON) }}$ | NC, NO, COM ON capacitance | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}} \text { or } \mathrm{GND}, \\ & \mathrm{f}=10 \mathrm{MHz} \end{aligned}$ | See Figure 16 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 370 |  | pF |
| $\mathrm{C}_{1}$ | Digital input capacitance | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {CC }}$ or GND | See Figure 16 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 2.6 |  | pF |
| BW | Bandwidth | $\mathrm{R}_{\mathrm{L}}=50 \Omega,-3 \mathrm{~dB}$ | Switch ON, | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 17.5 |  | MHz |
| OISo | OFF isolation | $\mathrm{R}_{\mathrm{L}}=50 \Omega$, | $\begin{aligned} & \mathrm{f}=100 \mathrm{kHz}, \\ & \text { see Figure } 20 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3.3 V |  | -68 |  | dB |
| $\mathrm{X}_{\text {TALK }}$ | Crosstalk | $\mathrm{R}_{\mathrm{L}}=50 \Omega$, | $\mathrm{f}=100 \mathrm{kHz},$ see Figure 21 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | -76 |  | dB |
| THD | Total harmonic distortion | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}, \end{aligned}$ | $\mathrm{f}=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz},$ see Figure 23 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | .008\% |  |  |
| SUPPLY |  |  |  |  |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{CC}}$ | Positive supply current | $\mathrm{V}_{\mathrm{COM}}$ and $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}$ or GND, <br> $\mathrm{V}_{\mathrm{NC}}$ and $\mathrm{V}_{\mathrm{NO}}=$ Floating |  | $25^{\circ} \mathrm{C}$ | 3.6 V |  | 0.1 | 1.2 | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  |  |  | 1.3 |  |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}-5.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \text { or } \mathrm{GND}, \\ & \mathrm{~V}_{\mathrm{NC}} \text { and } \mathrm{V}_{\mathrm{NO}}=\text { Floating } \end{aligned}$ |  | Full | 3.6 V |  |  | 3.4 | $\mu \mathrm{A}$ |

### 6.7 Electrical Characteristics for 5-V Supply

$\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | TA | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\text {COM }}$, <br> $\mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{NC}}$ | Analog signal range |  |  |  |  | $V_{C C}-5.5$ |  | $\mathrm{V}_{\text {cc }}$ | V |
| $\mathrm{R}_{\text {on }}$ | ON-state resistance | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}, 1.6 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{CC}}=-5.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 4.5 V |  | 0.52 | 0.74 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.83 |  |
| $\Delta \mathrm{R}_{\text {on }}$ | ON-state resistance match between channels | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=1.6 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 4.5 V |  | 0.04 | 0.23 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.30 |  |
| $\mathrm{R}_{\text {on(flat) }}$ | ON-state resistance flatness | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}, 1.6 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{CC}}=-5.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | COM to NO or NC, see Figure 13 | $25^{\circ} \mathrm{C}$ | 4.5 V |  | 0.076 | 0.46 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.5 |  |
| $\mathrm{R}_{\text {SH }}$ | Shunt switch resistance | $\mathrm{I}_{\mathrm{NO}}$ or $\mathrm{I}_{\mathrm{NC}}=10 \mathrm{~mA}$ |  | Full | 4.5 V |  | 16 | 36 | $\Omega$ |
| $\mathrm{I}_{\text {Com(ON }}$ | COM <br> ON leakage current | $\mathrm{V}_{\mathrm{NC}}$ and $\mathrm{V}_{\mathrm{NO}}=$ Open, <br> $\mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \mathrm{V}_{\mathrm{CC}}-5.5 \mathrm{~V}$, | See Figure 15 | $25^{\circ} \mathrm{C}$ | 5.5 V | -50 |  | 50 | nA |
|  |  |  |  | Full |  | -375 |  | 375 |  |
| DIGITAL CONTROL INPUTS (IN) ${ }^{(2)}$ |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{1 \mathrm{H}}$ | Input logic high |  |  | Full |  | 2.4 |  | 5.5 | V |
| $\mathrm{V}_{\mathrm{IL}}$ | Input logic low |  |  |  |  |  |  | 0.8 |  |
| $\mathrm{IIH}, \mathrm{I}_{\text {IL }}$ | Input leakage current | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {CC }}$ or 0 |  | $25^{\circ} \mathrm{C}$ | 5.5 V | -250 |  | 250 | nA |
|  |  |  |  | Full |  | -250 |  | 250 |  |
| DYNAMIC |  |  |  |  |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{ON}}$ | Turnon time | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ & \text { see Figure } 17 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 5 V |  | 27 | 80 | ns |
|  |  |  |  | Full | $\begin{aligned} & 4.5 \mathrm{~V} \text { to } \\ & 5.5 \mathrm{~V} \end{aligned}$ |  |  | 80 |  |
| toff | Turnoff time | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \end{aligned}$ | $\begin{aligned} & C_{\mathrm{L}}=35 \mathrm{pF} \\ & \text { see Figure } 17 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 5 V |  | 13 | 70 | ns |
|  |  |  |  | Full | $\begin{gathered} 4.5 \mathrm{~V} \text { to } \\ 5.5 \mathrm{~V} \end{gathered}$ |  |  | 70 |  |
| $\mathrm{t}_{\text {BBM }}$ | Break-beforemake time | $\begin{aligned} & V_{\mathrm{NC}}=\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}} / 2 \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$, | $25^{\circ} \mathrm{C}$ | 5 V | 1 | 3.5 |  | ns |
| Q | Charge injection | $\begin{aligned} & V_{\mathrm{GEN}}=0, \\ & \mathrm{R}_{\mathrm{GEN}}=0, \end{aligned}$ | $\begin{aligned} & C_{L}=1 \mathrm{nF}, \\ & \text { see Figure } 22 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 5 V |  | 500 |  | pC |
| $\mathrm{C}_{\text {COM(ON) }}$ | NC, NO, COM ON capacitance | $\mathrm{V}_{\text {COM }}=\mathrm{V}_{\text {CC }}$ or GND, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 5 V |  | 370 |  | pF |
| $\mathrm{C}_{1}$ | Digital input capacitance | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {CC }}$ or GND | See Figure 16 | $25^{\circ} \mathrm{C}$ | 5 V |  | 2.6 |  | pF |
| BW | Bandwidth | $\mathrm{R}_{\mathrm{L}}=50 \Omega$, |  | $25^{\circ} \mathrm{C}$ | 5 V |  | 18.3 |  | MHz |
| $\mathrm{O}_{\text {ISo }}$ | OFF isolation | $\mathrm{R}_{\mathrm{L}}=50 \Omega$, | $\begin{aligned} & \mathrm{f}=100 \mathrm{kHz}, \\ & \text { see Figure } 20 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 5 V |  | -70 |  | dB |
| $\mathrm{X}_{\text {talk }}$ | Crosstalk | $\mathrm{R}_{\mathrm{L}}=50 \Omega$, | $\begin{aligned} & f=100 \mathrm{kHz}, \\ & \text { see Figure } 21 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 5 V |  | -78 |  | dB |
| THD | Total harmonic distortion | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}, \end{aligned}$ | $\begin{aligned} & \mathrm{f}=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz}, \\ & \text { see Figure } 23 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 5 V |  | 009\% |  |  |
| SUPPLY |  |  |  |  |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{CC}}$ | Positive supply current | $\mathrm{V}_{\mathrm{COM}}$ and $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND, <br> $\mathrm{V}_{\mathrm{NC}}$ and $\mathrm{V}_{\mathrm{NO}}=$ Floating |  | $25^{\circ} \mathrm{C}$ | 5.5 V |  | 0.2 | 1.3 | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  |  |  | 3.5 |  |
|  |  | $\begin{aligned} & V_{C O M}=V_{C C}-5.5, \\ & V_{I N}=V_{C C} \text { or } G N D, \\ & V_{N C} \text { and } V_{N O}=\text { Floating } \end{aligned}$ |  | Full |  |  |  | 5 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at $\mathrm{V}_{\mathrm{CC}}$ or GND to ensure proper device operation. Floating digital inputs will cause excessive current consumption. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

### 6.8 Typical Characteristics



Figure 1. $\mathrm{R}_{\text {on }}$ vs $\mathrm{V}_{\text {com }}$


Figure 3. $\mathrm{R}_{\mathrm{on}} \mathrm{vs} \mathrm{V}_{\mathrm{COM}}\left(\mathrm{V}_{\mathrm{cc}}=3.3 \mathrm{~V}\right)$


Figure 5. Insertion Loss


Figure 2. $\mathrm{R}_{\mathrm{on}}$ vs $\mathrm{V}_{\mathrm{COM}}\left(\mathrm{V}_{\mathrm{CC}}=\mathbf{2 . 7} \mathrm{V}\right)$


Figure 4. $\mathrm{R}_{\mathrm{on}}$ vs $\mathrm{V}_{\text {com }}\left(\mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V}\right)$


Figure 6. Off Isolation vs Frequency

## Typical Characteristics (continued)



Figure 7. Charge Injection $\left(Q_{C}\right)$ vs $V_{\text {com }}$


Figure 9. Total Harmonic Distortion vs Frequency


Figure 11. $\mathrm{T}_{\mathrm{ON}}$ and $\mathrm{T}_{\text {OFF }}$ vs Supply Voltage


Figure 8. Crosstalk ( $\mathrm{V}_{\mathrm{Cc}}=3.3 \mathrm{~V}$ )


Figure 10. Power-Supply Current vs $\mathrm{V}_{\mathrm{CC}}$


Figure 12. $\mathrm{T}_{\mathrm{ON}}$ and $\mathrm{T}_{\text {OFF }}$ vs Temperature (2.5-V Supply)

## 7 Parameter Measurement Information



Figure 13. ON-State Resistance ( $\mathrm{R}_{\mathrm{on}}$ )


Figure 14. OFF-State Leakage Current (ICOM(OFF), $\left.I_{\text {NO(OFF) }}\right)$


Figure 15. ON-State Leakage Current
(ICOM(ON), $I_{\text {NO(ON) }}$ )

## Parameter Measurement Information (continued)


$\mathrm{V}_{\mathrm{BIAS}}=\mathrm{V}_{\mathrm{CC}}$ or GND and
$\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {IH }}$ or $\mathrm{V}_{\text {IL }}$
Capacitance is measured at NO, COM, and IN inputs during ON and OFF conditions.

Figure 16. Capacitance
( $\mathrm{C}_{\mathrm{l}}, \mathrm{C}_{\text {COM(OFF) }}, \mathrm{C}_{\text {COM(ON) }}, \mathrm{C}_{\text {NO(OFF) }}, \mathrm{C}_{\text {NO(ON) }}$ )

A. All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.
B. $C_{L}$ includes probe and jig capacitance.

Figure 17. Turnon ( $\mathrm{t}_{\mathrm{ON}}$ ) and Turnoff Time ( $\mathrm{t}_{\mathrm{OFF}}$ )

TS5A22364
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## Parameter Measurement Information (continued)


A. $\quad C_{L}$ includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.

Figure 18. Break-Before-Make Time ( $\mathrm{t}_{\mathrm{BBM}}$ )


Channel ON:NO to COM
$\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$

Network Analyzer Setup
Source power $=0 \mathrm{dBm}$ ( $632-\mathrm{mV}$ P-P at $50-\Omega$ load) DC Bias $=350 \mathrm{mV}$

Channel OFF: NO to COM $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$

NetworkAnalyzerSetup Source power $=0 \mathrm{dBm}$ (632-mV P-P at $50-\Omega$ load) DC bias $=350 \mathrm{mV}$

Figure 20. OFF Isolation ( $\mathrm{O}_{\text {Iso }}$ )

## Parameter Measurement Information (continued)



Figure 21. Crosstalk ( $\mathrm{X}_{\text {TALK }}$ )

A. All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.
B. $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 22. Charge Injection $\left(\mathbf{Q}_{\mathrm{C}}\right)$

$C_{L}$ includes probe and jig capacitance.
Figure 23. Total Harmonic Distortion (THD)

## 8 Detailed Description

### 8.1 Overview

The TS5A22364 is a bidirectional 2-channel, single-pole, double-throw (SPDT) analog switch designed to operate from $2.3-\mathrm{V}$ to $5.5-\mathrm{V}$ power supply. The device features negative signal swing capability that allows signals below ground to pass through the switch without distortion. Additionally, the TS5A22364 includes an internal shunt switch, which automatically discharges any capacitance at the NC or NO terminals when they are not connected to COM. Discharging the capacitance reduces the audible click and pop noise when switching between two sources. The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance are ideal for audio applications.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

### 8.3.1 Click and Pop Reduction

The shunt resistors in the TS5A22364 automatically discharge any capacitance at the NC or NO terminals when they are not connected to COM. This reduces the audible click-and-pop sounds that occur when switching between audio sources. Audible clicks and pops are caused when a step DC voltage is switched into the speaker. By automatically discharging the side that is not connected, any residual DC voltage is removed, thereby reducing the clicks and pops.

### 8.3.2 Negative Signal Swing Capability

The TS5A22364 2-channel SPDT switch features negative signal capability that allows signals below ground to pass through without distortion. These analog switches operate from a single $2.3-\mathrm{V}$ to $5.5-\mathrm{V}$ supply. The input and output signal swing of the device is dependant of the supply voltage $\mathrm{V}_{\mathrm{cc}}$. The device passes signals as high as $\mathrm{V}_{\mathrm{cc}}$ and as low as $\mathrm{V}_{\mathrm{cc}}-5.5 \mathrm{~V}$, including signals below ground with minimal distortion. The OFF state signal path (either NC or NO) during the operation of TS5A22364 cannot handle negative DC voltage
Table 1 shows the input/output signal swing the user can get with different supply voltages.
Table 1. Input/Output Signal Swing

| SUPPLY VOLTAGE, $\mathbf{V}_{\mathbf{C C}}$ | MINIMUM <br> $\mathbf{V}_{\mathbf{N C}}, \mathbf{V}_{\mathbf{N O}}, \mathbf{V}_{\mathbf{C O M}}=\mathbf{V}_{\mathbf{C C}}-5.5 \mathrm{~V}$ |  |
| :---: | :---: | :---: |
|  | ONAXIMUM <br> $\mathbf{V}_{\mathbf{N C}}, \mathbf{V}_{\mathbf{N O}}, \mathbf{V}_{\mathbf{C O M}}=\mathbf{V}_{\mathbf{C C}}$ |  |
| 5.5 V | 0 V | 5.5 V |
| 4.5 V | -1.0 V | 4.5 V |
| 3.6 V | -1.9 V | 3.6 V |
| 3.0 V | -2.5 V | 3.0 V |
| 2.7 V | -2.8 V | 2.7 V |
| 2.3 V | -3.2 V | 2.3 V |

### 8.4 Device Functional Modes

The function table for TS5A22364 is shown in Table 2.
Table 2. Function Table

| IN | NC TO COM, <br> COM TO NC | NO TO COM, <br> COM TO NO |
| :---: | :---: | :---: |
| L | ON | OFF |
| $H$ | OFF | ON |

## 9 Application and Implementation

## NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The shunt resistors on the TS5A22364 automatically discharge any capacitance at the NC or NO terminals when they are not connected to COM. This reduces audible click-and-pop sounds that occur when switching between audio sources. Audible clicks and pops are caused when a step DC voltage is switched into the speaker. By automatically discharging the side that is not connected, any residual DC voltage is removed, thereby reducing the clicks and pops.

### 9.2 Typical Application

The shunt resistors on the TS5A22364 are designed to automatically discharge any residual charge at the NC or NO terminals when they are not connected to COM. This reduces audible click-and-pop sounds that occur when switching between audio sources. Audible clicks and pops are caused when a step DC voltage is switched into the speaker. By automatically discharging the side that is not used for the signal path, any residual charge voltage is discharged to ground, thereby reducing the clicks and pops. The amount of power that the shunt switch can discharge from the inactive signal path is limited by the shunt resistors (Rsh) power dissipation. TI recommends that during operation, the current through the shunt path should be limited to $\pm 10 \mathrm{~mA}$.


Figure 24. Shunt Switch (TS5A22364)

## Typical Application (continued)

### 9.2.1 Design Requirements

Tie the digitally controlled inputs select pins IN1 and IN2 to $\mathrm{V}_{\mathrm{CC}}$ or GND to avoid unwanted switch states and high current consumption that could result if the logic control pins are left floating.

### 9.2.2 Detailed Design Procedure

Select the appropriate supply voltage to cover the entire voltage swing of the signal passing through the switch because the TS5A22364 operates from a single 2.3-V to $5.5-\mathrm{V}$ supply and the input and output signal swing of the device is dependant of the supply voltage, $\mathrm{V}_{\mathrm{CC}}$. The device will pass signals as high as $\mathrm{V}_{\mathrm{CC}}$ and as low as $\mathrm{V}_{\mathrm{cc}}-5.5 \mathrm{~V}$. Use Table 1 as a guide for selecting supply voltage based on the signal passing through the ONstate switch path.
Ensure that the device is powered up with a valid supply voltage on VCC before a voltage can be applied to the signal paths NC and NO.

### 9.2.3 Application Curve



Figure 25. $\mathbf{R}_{\text {on }}$ vs $\mathrm{V}_{\text {com }}$

## 10 Power Supply Recommendations

The TS5A22364 operates from a single $2.3-\mathrm{V}$ to $5.5-\mathrm{V}$ supply. The device must be powered up with a supply voltage on VCC before a voltage can be applied to the signal paths NC and NO. TI recommends to include a $100-\mu \mathrm{s}$ delay after VCC is at voltage before applying a signal on NC and NO paths
It is also good practice to place a $0.1-\mu \mathrm{F}$ bypass capacitor on the supply pin VCC to GND to smooth out lower frequency noise to provide better load regulation across the frequency spectrum.

## 11 Layout

### 11.1 Layout Guidelines

TI recommends placing a bypass capacitor as close to the supply pin VCC as possible to help smooth out lower frequency noise to provide better load regulation across the frequency spectrum.
Minimize trace lengths and vias on the signal paths in order to preserve signal integrity.

### 11.2 Layout Example



Figure 26. Layout Example of TS5A22364

## 12 Device and Documentation Support

### 12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E ${ }^{\text {TM }}$ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.
Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.3 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

### 12.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.5 Glossary

SLYZ022 - TI Glossary.
This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <br> (2) | Lead/Ball Finish <br> (6) | MSL Peak Temp <br> (3) | Op Temp ( ${ }^{\circ} \mathrm{C}$ ) | Device Marking <br> (4/5) | Samples |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS5A22364DGSR | ACTIVE | VSSOP | DGS | 10 | 2500 | Green (RoHS \& no $\mathrm{Sb} / \mathrm{Br}$ ) | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | (38Q, 38R) | Samples |
| TS5A22364DRCR | ACTIVE | VSON | DRC | 10 | 3000 | Green (RoHS \& no $\mathrm{Sb} / \mathrm{Br}$ ) | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | ZVF | Samples |
| TS5A22364YZPR | ACTIVE | DSBGA | YZP | 10 | 3000 | Green (RoHS \& no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | $(38,382)$ | Samples |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but Tl does not recommend using this part in a new design
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device
${ }^{(2)}$ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. Tl may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption
Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.
${ }^{(3)}$ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
${ }^{(4)}$ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
${ }^{(5)}$ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
${ }^{(6)}$ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

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OTHER QUALIFIED VERSIONS OF TS5A22364 :

- Automotive: TS5A22364-Q1

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects


## TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package <br> Type | Package <br> Drawing | Pins | SPQ | Reel <br> Diameter <br> $(\mathbf{m m})$ | Reel <br> Width <br> $\mathbf{W 1}(\mathbf{m m})$ | A0 <br> $(\mathbf{m m})$ | B0 <br> $(\mathbf{m m})$ | K0 <br> $(\mathbf{m m})$ | P1 <br> $(\mathbf{m m})$ | W <br> $(\mathbf{m m})$ | Pin1 <br> Quadrant |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS5A22364DGSR | VSSOP | DGS | 10 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TS5A22364DRCR | VSON | DRC | 10 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TS5A22364YZPR | DSBGA | YZP | 10 | 3000 | 178.0 | 9.2 | 1.49 | 1.99 | 0.63 | 4.0 | 8.0 | Q2 |


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS5A22364DGSR | VSSOP | DGS | 10 | 2500 | 358.0 | 335.0 | 35.0 |
| TS5A22364DRCR | VSON | DRC | 10 | 3000 | 367.0 | 367.0 | 35.0 |
| TS5A22364YZPR | DSBGA | YZP | 10 | 3000 | 220.0 | 220.0 | 35.0 |



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.


NOTES: (continued)
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.

For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).


SOLDER PASTE EXAMPLE BASED ON 0.1 mm THICK STENCIL SCALE:30X

NOTES: (continued)
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.


## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.


NOTES: (continued)
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.


SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL SCALE:10X

NOTES: (continued)
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.


NOTES: (continued)
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
EXPOSED PAD 11:
80\% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

NOTES: (continued)
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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[^0]:    (1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
    (2) All unused digital inputs of the device must be held at $\mathrm{V}_{\mathrm{CC}}$ or GND to ensure proper device operation. Floating digital inputs will cause excessive current consumption. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

